NSN 5961-00-891-8663

Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
1.218 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
1.250 inches
Thread Size:
0.750 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
200.0 breakover voltage, dc
Current Rating Per Characteristic:
1500.00 amperes source cutoff current preset
Power Rating Per Characteristic:
2.0 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius case
Special Features:
Junction pattern arrangement: npn
Thread Series Designator:
Unf
Terminal Type And Quantity:
3 tab, solder lug and 1 threaded stud
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0